



# P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
- 20	0.0073 at V <sub>GS</sub> = - 4.5 V	- 20		
	0.0090 at V <sub>GS</sub> = - 2.5 V	- 18		
	0.013 at V <sub>GS</sub> = - 1.8 V	- 15		

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFETs
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile

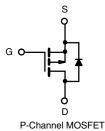


FREE

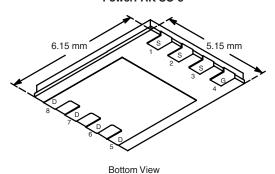
#### **APPLICATIONS**

· Battery Switch for Portable Devices





#### PowerPAK SO-8



Ordering Information: Si7485DP-T1-E3 (Lead (Pb)-free)

Si7485DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 20		V
Gate-Source Voltage		V <sub>GS</sub>	± 8		
Continuous Drain Current /T 150 °C\a	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 20	- 12.5	А
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 16.5	- 9.5	
Pulsed Drain Current		I <sub>DM</sub>	- 50		А
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 4.5	- 1.6	
Manipular Davida Disabation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	5	1.8	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		3.2	1.1	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature)b,c			2	260	C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian de Ambienta	t ≤ 10 s	R <sub>thJA</sub>	20	25	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		54	68	
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.7	2.2	]

#### Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<a href="https://www.vishay.com/ppg?73257">www.vishay.com/ppg?73257</a>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# Vishay Siliconix



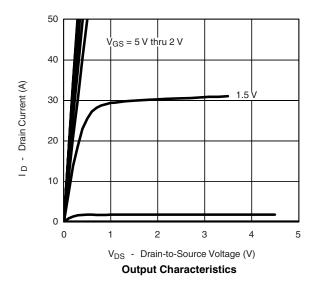
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Condition Min.		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -1$ mA	- 0.4		- 0.9	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 20 V, V <sub>GS</sub> = 0 V			- 1		
		$V_{DS}$ = - 20 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			- 10	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge -5 V$ , $V_{GS} = -4.5 V$	- 40			Α	
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 20 A		0.006	0.0073		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 18 A		0.0074	0.0090	Ω	
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 15 A		0.0106	0.013		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 20 A		80		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 4.5 A, V <sub>GS</sub> = 0 V		- 0.62	- 1.1	V	
Dynamic <sup>b</sup>			•	•			
Total Gate Charge	$Q_g$			99	150		
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ = - 10 V, $V_{GS}$ = - 5 V, $I_D$ = - 20 A		11.5		nC	
Gate-Drain Charge	Q <sub>gd</sub>			29			
Gate Resistance	$R_{g}$			2.4		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			80	120		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 10 V, $R_L$ = 10 $\Omega$		140	210	. ns	
Turn-Off Delay Time		$I_D \cong -1$ A, $V_{GEN} = -4.5$ V, $R_g = 6 \Omega$		360	540		
Fall Time				170	260		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = -2.9 \text{ A, dI/dt} = 100 \text{ A/}\mu\text{s}$		55	80		

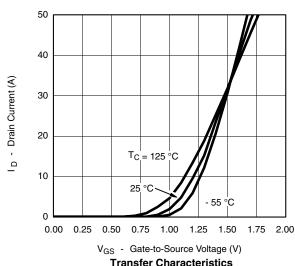
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





**Transfer Characteristics** 

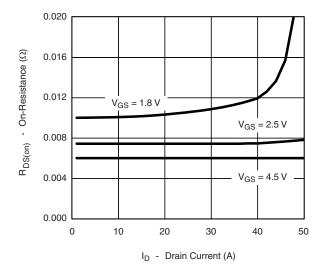




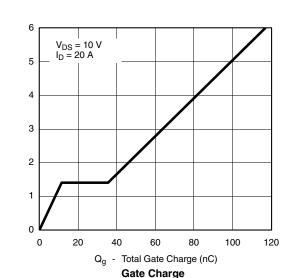


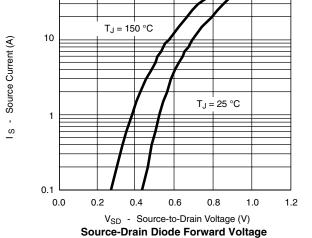
V<sub>GS</sub> - Gate-to-Source Voltage (V)

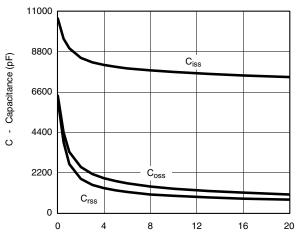
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current

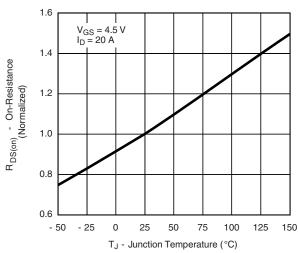




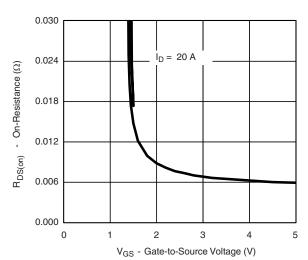


V<sub>DS</sub> - Drain-to-Source Voltage (V)

Capacitance



**On-Resistance vs. Junction Temperature** 



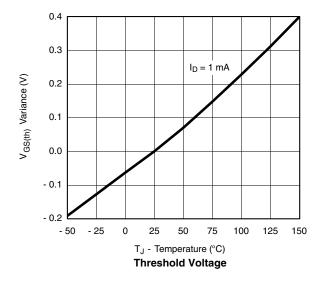
On-Resistance vs. Gate-to-Source Voltage

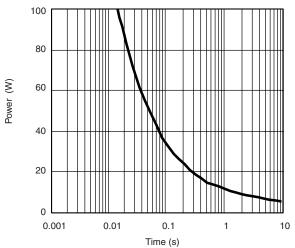
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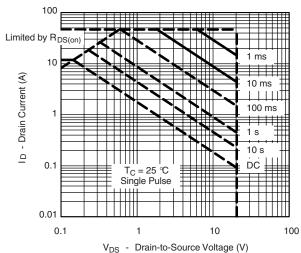
# VISHAY.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

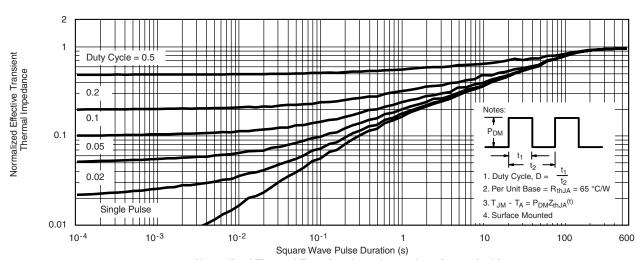




Single Pulse Power, Junction-to-Ambient



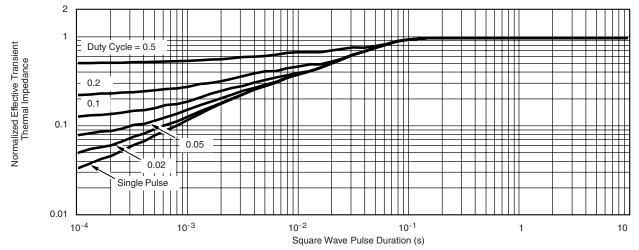
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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